

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
-20V	400mΩ@-4.5V	-0.7A
	550mΩ@-2.5V	

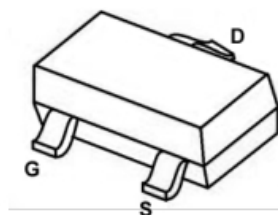
Feature

- Surface Mount Package
- P-Channel Switch with Low $R_{DS(on)}$
- Operated at Low Logic Level Gate Drive
- ESD Protected

Applications

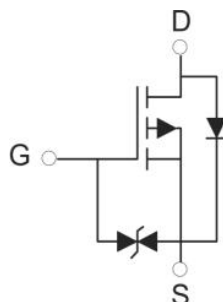
- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable Electronics

Package

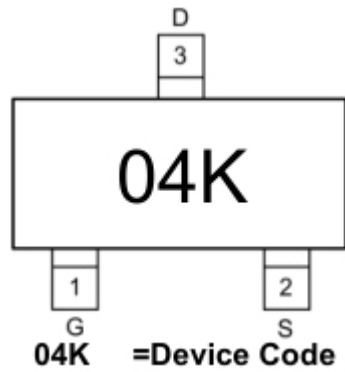


SOT-23

Circuit diagram



Marking



Absolute maximum ratings

($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	± 10	V
Continuous Drain Current	I_D	-0.7	A
Pulsed Drain Current	I_{DM}	-1.2	A
Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	$^{\circ}\text{C}/\text{W}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	$T_{STG.}$	-55~ +150	$^{\circ}\text{C}$

Electrical characteristics

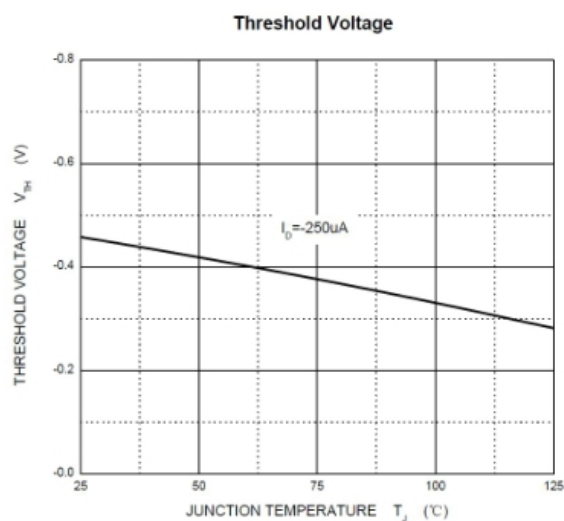
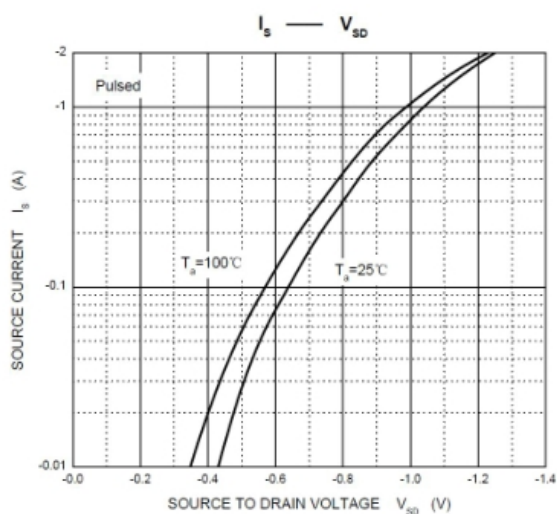
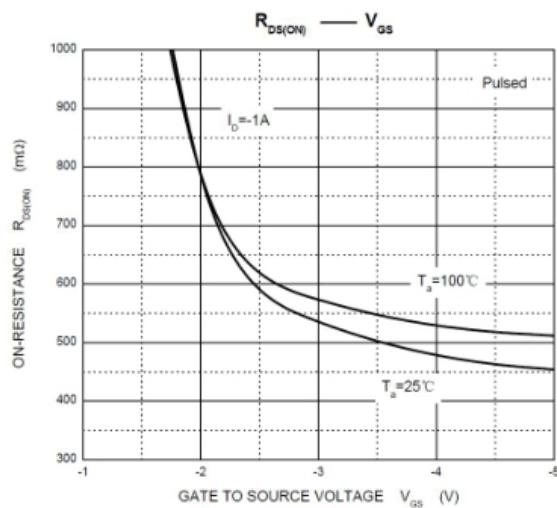
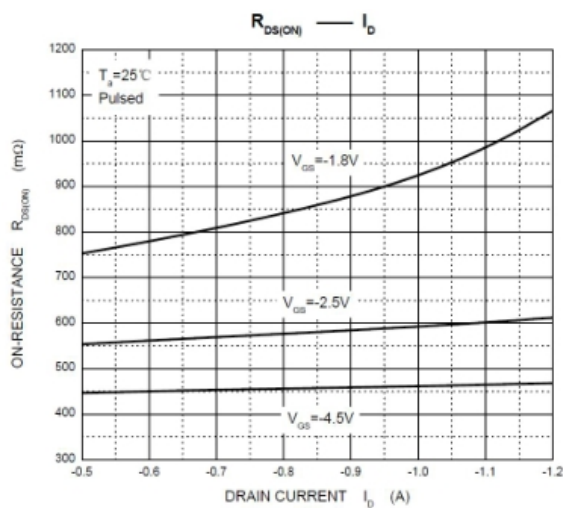
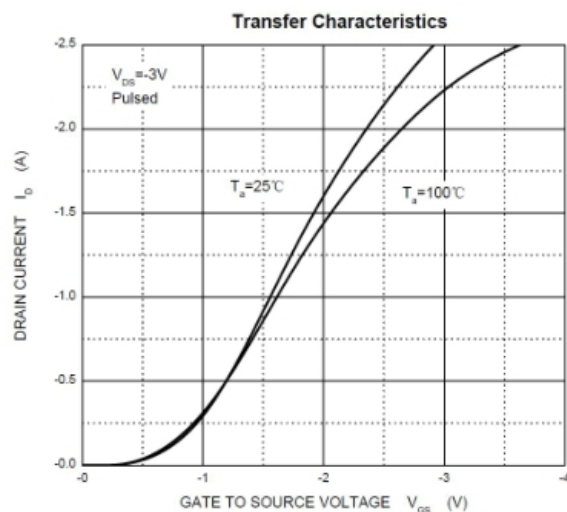
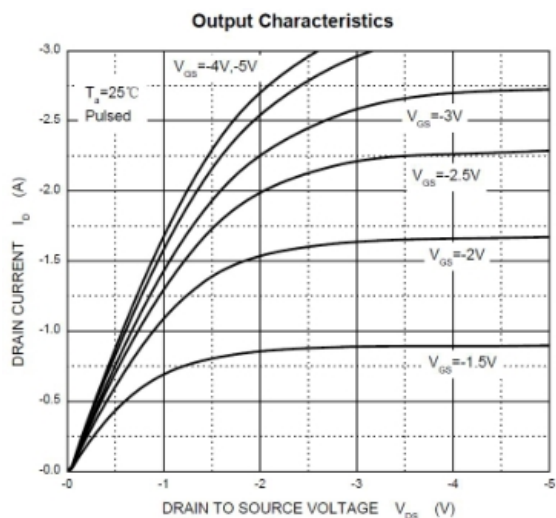
(T_A=25°C, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	BV (BR) _{DSS}	V _{GS} = 0V, I _D = -250μA	-20			V
Zero gate voltage drain current	I _{DSS}	V _{DS} = -20V, V _{GS} = 0V			-1	uA
Gate-body leakage current	I _{GSS}	V _{GS} = ±10V, V _{DS} = 0V			±10	uA
Gate threshold voltage ⁽¹⁾	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250μA	-0.35	-0.65	-1	V
Drain-source on-resistance ⁽¹⁾	R _{DS(on)}	V _{GS} = -4.5V, I _D = -0.5A		400	550	mΩ
		V _{GS} = -2.5V, I _D = -0.2A		550	700	
Dynamic Characteristics						
Input capacitance	C _{iSS}	V _{DS} = -16V, V _{GS} =0V, f=1MHz		113		pF
Output capacitance	C _{oss}			15		
Reverse transfer capacitance	C _{rSS}			9		
Turn-on Delay Time	T _{d(on)}	V _{DS} = -10V, I _D = - 200mA , V _{GS} = -4.5V, R _{GEN} =10Ω		9		nS
Turn-on Rise Time	T _r			5.7		
Turn-Off Delay Time	T _{d(off)}			32.6		
Turn-Off Fall Time	t _f			20.3		
Source-Drain Diode Characteristics						
Body Diode Voltage	V _{SD}	I _S = -0.5A, V _{GS} = 0V			-1.2	V

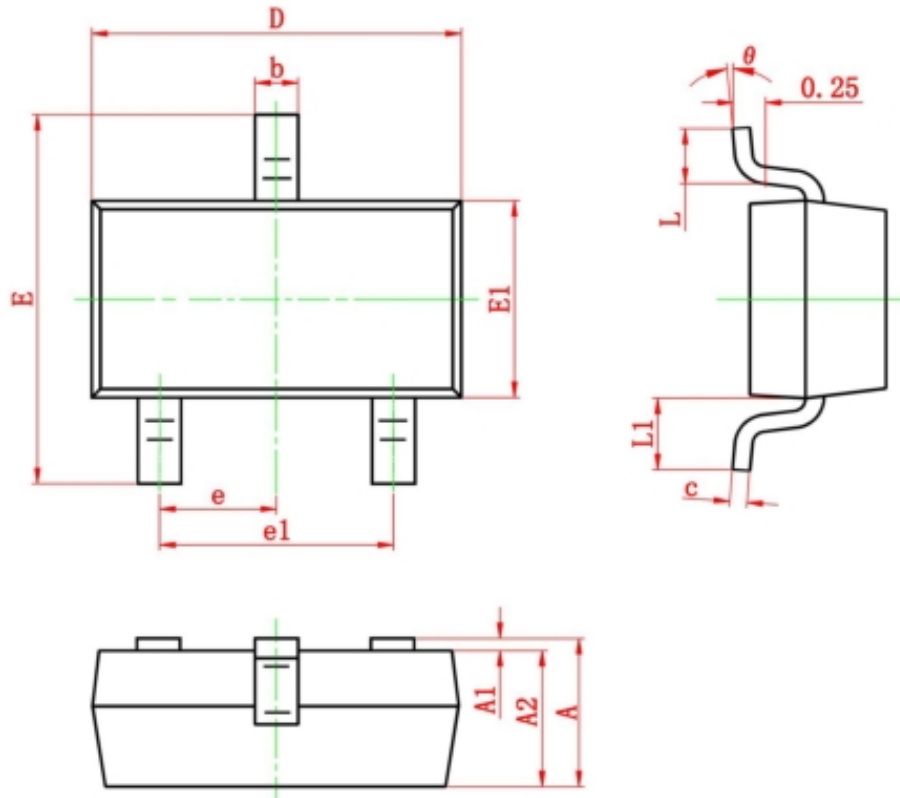
Notes:

1. Pulse Test: Pulse Width < 300μs, Duty Cycle ≤ 2%.
2. Guaranteed by design, not subject to production testing.

Typical Characteristics



SOT-23 Package Information



Symbol	Dimensions In Millimeters	
	Min.	Max.
A	0.90	1.15
A1	0.00	0.10
A2	0.90	1.05
b	0.30	0.50
c	0.08	0.15
D	2.80	3.00
E	1.20	1.40
E1	2.25	2.55
e	0.95 REF.	
e1	1.80	2.00
L	0.55 REF.	
L1	0.30	0.50
θ	0°	8°